

### isc N-Channel Mosfet Transistor

## BUZ45A

#### • FEATURES

- Static Drain-Source On-Resistance
  - : R<sub>DS(on)</sub> = 0.8 Ω (Max)
- SOA is Power Dissipation Limited
- High speed switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

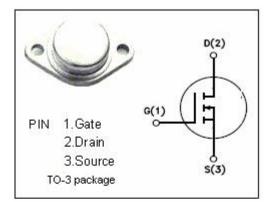
Designed for applications such as switching regulators, switching converters, motor drivers, relay drivers and drivers for high power bipolar switching transistors requiring high speed and low gate drive power.

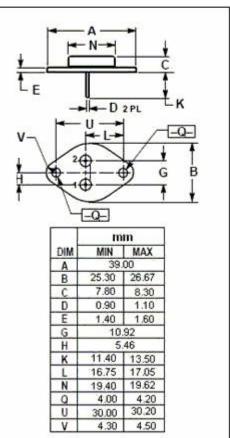
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)								
SYMBOL	ARAMETER	VALUE	UNIT					
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0)	500	V					
$V_{GS}$	Gate-Source Voltage	±20	V					
ID	Drain Current-continuous@ TC=25℃	8.3	А					
P <sub>tot</sub>	Total Dissipation@TC=25°C	125	W					
Tj	Max. Operating Junction Temperature	150	°C					
T <sub>stg</sub>	Storage Temperature Range	-55~150	Ĉ					

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.0	°C/W
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	35	°C/W

1





### isc website: www.iscsemi.com



## isc N-Channel Mosfet Transistor

# BUZ45A

### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	500		V
V <sub>GS(TH)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 1mA	2.1	4	V
Rds(on)	Drain-Source On-stage Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 5A		0.8	Ω
I <sub>GSS</sub>	Gate Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0		250	uA
V <sub>SD</sub>	Diode Forward Voltage	I⊧= 16.6A; V <sub>GS</sub> = 0		1.6	V

### **NOTICE:**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

2